# NSN 5962-01-273-6754

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

Between 0.930 inches and 0.975 inches

## **Body Width:**

Between 0.245 inches and 0.300 inches

# **Body Height:**

0.180 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# **Features Provided:**

Programmable and schottky and low current

## **Inclosure Material:**

Ceramic and glass

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

10 input

# **Current Rating Per Characteristic:**

155.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

4.5 volts power source and 55.5 volts power source

## **Time Rating Per Chacteristic:**

35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Prom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

18 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

## Fiig:

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